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Vishay Semiconductors

Ultrafast Soft Recovery Diode, 60 A FRED Pt®





TO-247 long lead 2-pins

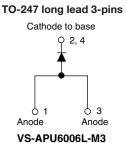
Cathode to base

2

1

3
Cathode Anode

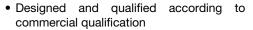
VS-EPU6006L-M3



PRODUCT SUMMARY					
Package	TO-247 long lead 2 pins,				
Fackage	TO-247 long lead 3 pins				
I _{F(AV)}	60 A				
V_{R}	600 V				
V _F at I _F	1.05 V				
t _{rr} typ.	32 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature









ROHS COMPLIANT HALOGEN FREE

DESCRIPTION / APPLICATIONS

VS-EPU60/VS-APU60... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, welding, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Repetitive peak reverse voltage	V_{RRM}		600	V		
Average rectified forward current in DC	I _{F(AV)}	T _C = 116 °C	60	۸		
Single pulse forward current	I _{FSM}	T _C = 25 °C	600	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage		I _F = 60 A	-	1.2	1.5	V	
	V_{F}	I _F = 60 A, T _J = 125 °C	-	1.1	1.3		
		I _F = 60 A, T _J = 175 °C	-	1.05	1.2		
Reverse leakage current	,	V _R = V _R rated	-	0.2	30	^	
	I _R	T _J = 150 °C, V _R = V _R rated	-	-	200	μΑ	
Junction capacitance	C _T	V _R = 600 V	-	38	-	pF	



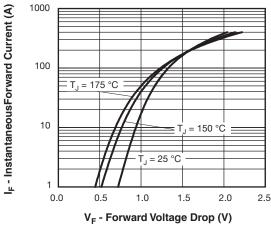
VS-EPU6006L-M3, VS-APU6006L-M3

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt = 20$	00 A/μs, V _R = 30 V	-	32	-	
Reverse recovery time	Reverse recovery time t_{rr}	T _J = 25 °C		-	110	-	ns
		T _J = 125 °C	$I_F = 60 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	200	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	10	-	А
		T _J = 125 °C		-	19	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	530	-	nC
		T _J = 125 °C		-	1900	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	-	0.65	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Maight			-	6	-	g
Weight			-	0.21	-	oz.
Mounting torque			6 (5)	-	1.2 (10)	kgf. cm (lbf · in)
Marillan de Con		Case style TO-247 long lead 2 pins	EPU6006L			
Marking device		Case style TO-247 long lead 3 pins		APU	6006L	

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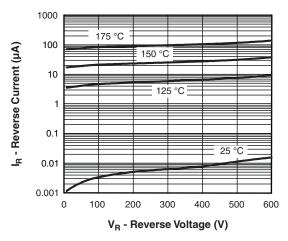


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

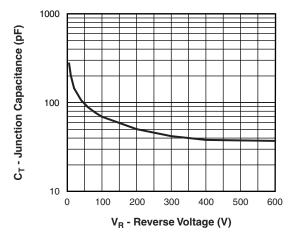


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

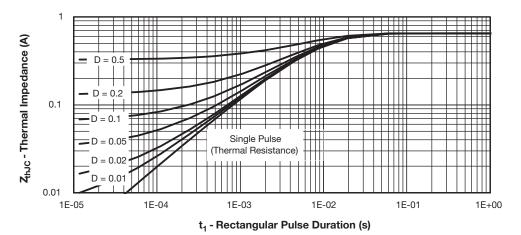


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

260



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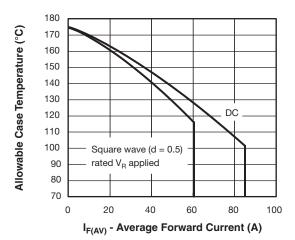


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

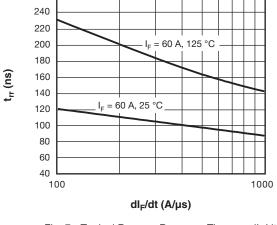


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

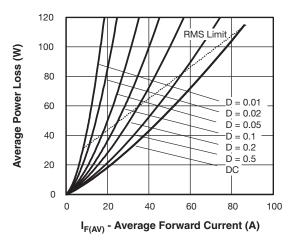


Fig. 6 - Forward Power Loss Characteristics

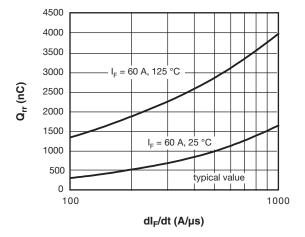


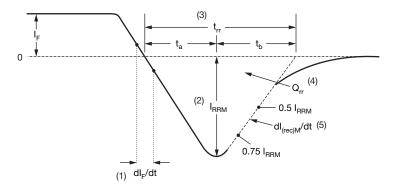
Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at} \ (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at} \ V_{R1} = 80 \ \% \ \text{rated} \ V_R \\ \end{array}$

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- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RRM}$

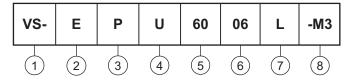
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dI_{(rec)M}/dt - peak rate of change of current during t_h portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Circuit configuration:
 - A = single diode 3-pin
 - E = single diode 2-pin
- **3** P = TO-247
- U = ultrafast recovery time
- 5 Current code (60 = 60 A)
- 6 Voltage code (06 = 600 V)
- 7 L = long lead
- 8 Environmental digit:
 - -M3 = halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-EPU6006L-M3	30	300	Antistatic plastic tube			
VS-APU6006L-M3	30	300	Antistatic plastic tube			

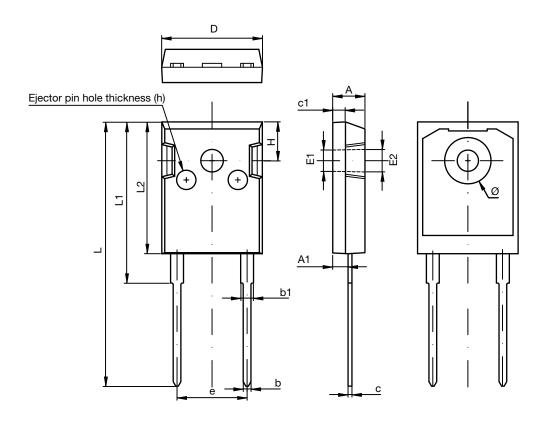
LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247 3-pin LL	www.vishay.com/doc?95599			
Dimensions	TO-247AC 2-pin LL	www.vishay.com/doc?95598			
Part marking information	TO-247 3-pin LL	www.vishay.com/doc?95593			
	TO-247 2-pin LL	www.vishay.com/doc?95592			



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TO-247AD 2L

DIMENSIONS in millimeters



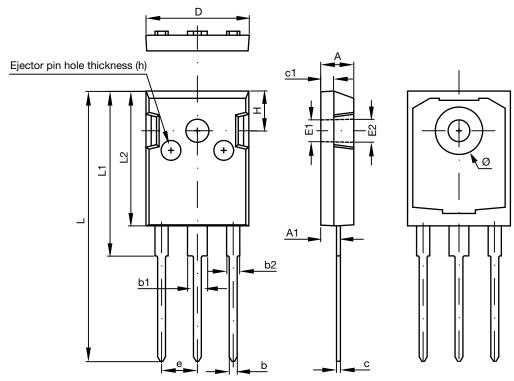
SYMBOL	DIMENSIONS I	N MILLIMETERS	DIMENSION	S IN INCHES
STINIBUL	MIN.	MAX.	MIN.	MAX.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.50	3.500 Ref.		Ref.
E2	3.60	0 Ref.	0.142 Ref.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Ø	7.100	7.300	0.280	0.287
е	10.90	10.900 Typ.		Тур.
Н	5.98	0 Тур.	0.235 Typ.	
h	0.000	0.300	0.000	0.012



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TO-247AD 3L

DIMENSIONS in millimeters



SYMBOL	DIMENSIONS I	N MILLIMETERS	DIMENSION	S IN INCHES
STWIBUL	MIN.	MAX.	MIN.	MAX.
Α	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	2.800	3.200	0.110	0.126
b2	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.50	000 Ref. 0.138 Ref.		Ref.
E2	3.60	0 Ref.	0.142 Ref.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Ø	7.100	7.300	0.280	0.287
е	5.450 Typ.		0.215	Тур.
Н	5.98	5.980 Typ.		Тур.
h	0.000	0.300	0.000	0.012

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